NSN 5961-01-047-7473

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-047-7473 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.050 inches and 0.080 inches Overall Diameter: Between 0.080 inches and 0.105 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 breakdown voltage, collector-to-base, emitter open and -40.0 breakdown voltage, collector-to-emitter, base open and -5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** -600.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 200.0 milliwatts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 05869-750511 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: